

Description

The FTE24C256 is an electrically erasable PROM device that uses the standard 2-wire interface for communications. The FTE24C256 contains a memory array of 256K-bits (32,768 x 8), and is further subdivided into 512 pages of 64 bytes each for Page-Write mode. This EEPROM is offered in wide operating voltages of 2.5V to 5.5V to be compatible with most application voltages. Force Technologies designed the FTE24C256 to be a low-cost and low-power 2-wire EEPROM solution. The devices are packaged in 8-pin Ceramic DIP, Flatpack, 20 Pin LCC and 8 pin Plastic DIP or SOIC.

The FTE24C256 maintains compatibility with the popular 2-wire bus protocol, so it is easy to design into applications implementing this bus type. The simple bus consists of the Serial Clock wire (SCL) and the Serial Data wire (SDA). Using the bus, a Master device such as a microcontroller is usually connected to one or more Slave devices such as the FTE24C256. The bit stream over the SDA line includes a series of bytes, which identifies a particular Slave device, an instruction, an address within that Slave device, and a series of data, if appropriate. The FTE24C256 has a Write Protect pin (WP) to allow blocking of any write instruction transmitted over the bus.

Two-Wire Serial Interface, I²C[™] compatible Bi-directional data transfer protocol

400 KHz (2.5V) and 1 MHz (5.0V) compatibility

Low Power CMOS Technology -Active Current less than 3 mA (5.0V) -Stanby Current less than 6 µA (5.0V) -Standby Current less than 2 µA (2.5V)

Wide Voltage Operation -Vcc = 2.5V to 5.5V

Hardware Data Protection -Write Protect Pin

Sequential Read Feature Filtered Inputs for Noise Suppression Self time write cycle with auto clear -5 ms @ 2.5V

Organisation:

-32Kx8 (512 pages of 64 bytes)

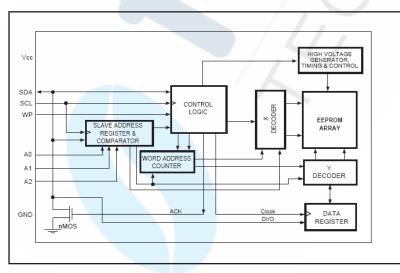
64 Byte Page Write Buffer

High Reliability

-Endurance: 100,000 Cycles

-Data Retention: 40 Years

Military and Extended temperature ranges



Function Block Diagram

DIP, SOIC, Flat Pack 8 Pin Package	LCC20 Pkg
1	5
2	6
3	7
4	10
5	15
6	16
7	17
8	20
	Flat Pack 8 Pin Package 1 2 3 4 5 6 7

Table 1. Pin Configurations



256K-bit 2-Wire Serial CMOS EEPROM

DEVICE OPERATION

The FTE24C256 features a serial communication and supports a bi-directional 2-wire bus transmission protocol called I^2C^{TM} .

2-WIRE BUS

The two-wire bus is defined as a Serial Data line (SDA), and a Serial Clock line (SCL). The protocol defines any device that sends data onto the SDA bus as a transmitter, and the receiving devices as receivers. The bus is controlled by Master device which generates the SCL, controls the bus access and generates the Stop and Start conditions. The FTE24C256 is the Slave device on the bus.

The Bus Protocol:

 Data transfer may be initiated only when the bus is not busy

- During a data transfer, the SDA line must remain stable whenever the SCL line is high. Any changes in the data line while the SCL line is high will be interpreted as a Start or Stop condition.

The state of the SDA line represents valid data after a Start condition. The SDA line must be stable for the duration of the High period of the clock signal. The data on the SDA line may be changed during the Low period of the clock signal. There is one clock pulse per bit of data. Each data transfer is initiated with a Start condition and terminated with a Stop condition.

Start Condition

The Start condition precedes all commands to the device and is defined as a High to Low transition of SDA when SCL is High. The FTE24C256 monitors the SDA and SCL lines and will not respond until the Start condition is met.

Stop Condition

The Stop condition is defined as a Low to High transition of SDA when SCL is High. All operations must end with a Stop condition.

Acknowledge (ACK)

After a successful data transfer, each receiving device is required to generate an ACK. The Acknowledging device pulls down the SDA line.

Reset

The FTE24C256 contains a reset function in case the 2- wire bus transmission is accidentally interrupted (eg. a power loss), or needs to be terminated mid-stream. The reset is caused when the Master device creates a Start condition. To do this, it may be necessary for the Master device to monitor the SDA line while cycling the SCL up to nine times. (For each clock signal transition to High, the Master checks for a High level on SDA.)

Standby Mode

Power consumption is reduced in standby mode. The FTE24C256 will enter standby mode: a) At Power-up, and remain in it until SCL or SDA toggles; b) Following the Stop signal if no write operation is initiated; or c) Following any internal write operation

DEVICE ADDRESSING

The Master begins a transmission by sending a Start condition. The Master then sends the address of the particular Slave devices it is requesting. The Slave device (Fig. 5) address is 8 bits. The four most significant bits of the Slave device address are fixed as 1010 for the FTE24C256.

This device has three address bits (A2, A1, and A0), which allows up to eight FTE24C256 devices to share the 2-wire bus. Upon receiving the Slave address, the device compares the three address bits with the hardwired A2, A1, and A0 input pins to determine if it is the appropriate Slave.

The last bit of the Slave address specifies whether a Read or Write operation is to be performed. When this bit is set to 1, a Read operation is selected, and when set to 0, a Write operation is selected.

After the Master transmits the Start condition and Slave address byte (Fig. 5), the appropriate 2-wire Slave (eg. FTE24C256) will respond with ACK on the SDA line. The Slave will pull down the SDA on the ninth clock cycle, signaling that it received the eight bits of



data. The selected FTE24C256 then prepares for a Read or Write operation by monitoring the bus.

WRITE OPERATION

Byte Write

In the Byte Write mode, the Master device sends the Start condition and the Slave address information (with the R/W set to Zero) to the Slave device. After the Slave generates an ACK, the Master sends the two byte address that are to be written into the address pointer of the FTE24C256. After receiving another ACK from the Slave, the Master device transmits the data byte to be written into the address memory location. The FTE24C256 acknowledges once more and the Master generates the Stop condition, at which time the device begins its internal programming cycle. While this internal cycle is in progress, the device will not respond to any request from the Master device.

Page Write

The FTE24C256 is capable of 64-byte Page-Write operation. A Page-Write is initiated in the same manner as a Byte Write, but instead of terminating the internal Write cycle after the first data word is transferred, the Master device can transmit up to 63 more bytes. After the receipt of each data word, the FTE24C256 responds immediately with an ACK on SDA line, and the six lower order data word address bits are internally incremented by one, while the higher order bits of the data word address remain constant. If a byte address is incremented from the last byte of a page. it returns to the first byte of that page. If the Master device should transmit more than 64 words prior to issuing the Stop condition, the address counter will "roll over," and the previously written data will be overwritten. Once all 64 bytes are received and the Stop condition has been sent by the Master, the internal programming cycle begins. At this point, all received data is written to the FTE24C256 in a single Write cycle. All inputs are disabled until completion of the internal Write cycle.

Acknowledge (ACK) Polling

The disabling of the inputs can be used to take advantage of the typical Write cycle time. Once the Stop condition is issued to indicate the end of the host's Write operation, the FTE24C256 initiates the internal Write cycle. ACK polling can be initiated immediately. This involves issuing the Start condition followed by the Slave address for a Write operation. If the FTE24C256 is still busy with the Write operation, no ACK will be returned. If the FTE24C256 has completed the Write operation, an ACK will be returned and the host can then proceed with the next Read or Write operation.

READ OPERATION

Read operations are initiated in the same manner as Write operations, except that the (R/W) bit of the Slave address is set to "1". There are three Read operation options: current address read, random address read, and sequential read.

Current Address Read

The FTE24C256 contains an internal address counter which maintains the address of the last byte accessed, incremented by one. For example, if the previous operation is either a Read or Write operation addressed to the address location n, the internal address counter would increment to address location n+1. When the FTE24C256 receives the Slave Device Addressing Byte with a Read operation (R/W bit set to "1"), it will respond an ACK and transmit the 8-bit data word stored at address location n+1. The Master should not acknowledge the transfer but should generate a Stop condition so the FTE24C256 discontinues transmission. If 'n' is the last byte of the memory, the data from location '0' will be transmitted. (Refer to Figure 8. Current Address Read Diagram.)

Random Address Read

Selective Read operations allow the Master device to select at random any memory location for a Read operation. The Master device first performs a 'dummy' Write operation by sending the Start condition, Slave address and word address of the location it wishes to read. After the FTE24C256 acknowledges the word address, the Master device resends the Start condition and the Slave address, this time with the R/W bit set to one. The FTE24C256 then responds with its ACK and sends the data requested. The Master device does not send an ACK but will generate a Stop condition. (Refer to Figure 9. RandomAddress Read Diagram.)



Sequential Read

Sequential Reads can be initiated as either a Current Address Read or Random Address Read. After the FTE24C256 sends the initial byte sequence, the Master device now responds with an ACK indicating it requires additional data from the FTE24C256. The FTE24C256 continues to output data for each ACK received. The Master device terminates the sequential Read operation by pulling SDA High (no ACK) indicating the last data word to be read, followed by a Stop condition. The data output is sequential, with the data from address n followed by the data from address n+1, ... etc. The address counter increments by one automatically, allowing the entire memory contents to be serially read during sequential Read operation. When the memory address boundary 32767 is reached, the address counter "rolls over" to address 0, and the FTE24C256 continues to output data for each ACK received. (Refer to Figure 10. Sequential Read Operation Starting with a Random Address Read Diagram.)



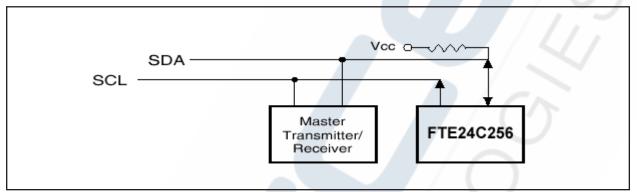


Figure 1. Typical System Bus Configuration

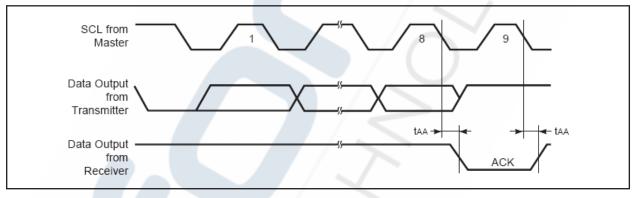


Figure 2. Output Acknowledge

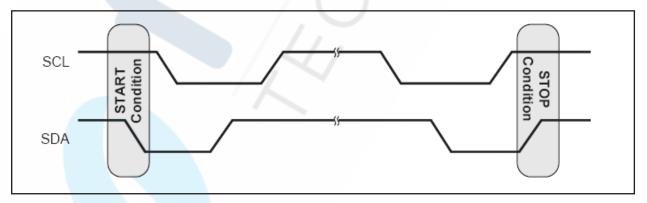


Figure 3. Start and Stop Conditions



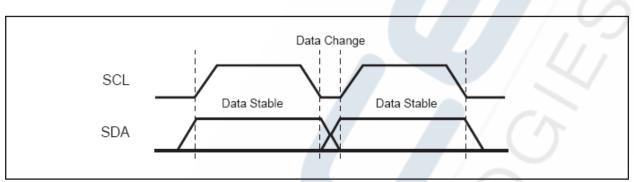


Figure 4. Data Validity Protocol

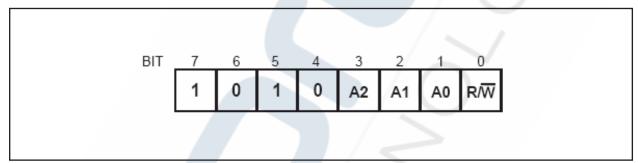


Figure 5. Slave Address

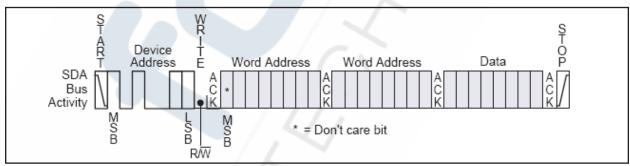


Figure 6. Byte Write

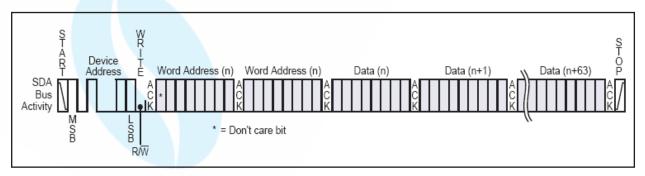


Figure 7. Page Write



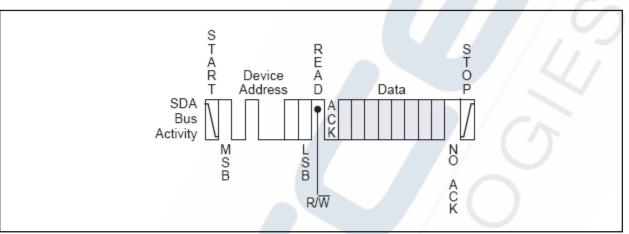


Figure 8. Current Address Read

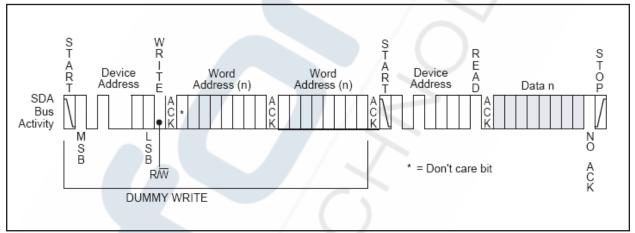


Figure 9. Random Address Read

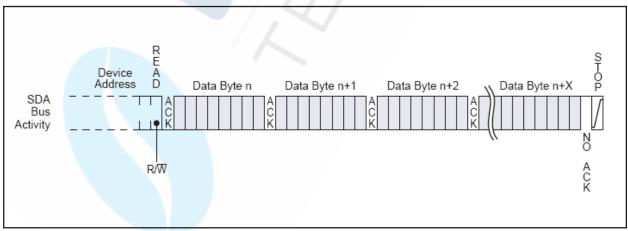


Figure10. Sequential Read



FT24C256 256K-bit 2-Wire Serial

CMOS EEPROM

A	Ratings ¹ ($T_A = 25^{\circ}C$)	111	
Supply Voltage (V _S)	+0.5 to +6.5 V	Storage Temperature (T _{STG})	-65 to +200°C
Voltage on Any Pin (V _P)	-0.5 to V _{CC} +0.5 V	Output Current (I _{OUT})	4 mA
Temperature UnderBias (T _{BIAS})	-55 to +175 °C		$(\land$

Recommended Operating Conditions						
Parameter	Symbol	Conditions	Min	Тур	Max	Units
Military	V _{CC}	-55 °C to +125 °C	2.5		5.5	V
Extended Temp	V _{CC}	-55 °C to +175 °C	4.5		5.5	V

	(Capacitance ^{2,3}		
Parameter	Symbol	Conditions	Max	Units
Input Capacitance	C _{IN}	V _{IN} = 0V	6	pF
Output Capacitance	C _{OUT}	V _{OUT} = 0V	8	pF

DC Electrical Characteristics (T_A =-55°C to +175°C)						
Parameter	Symbol	Conditions	Min Typ Max Units			
Output Low Voltage	V _{OL}	$V_{CC} = 2.5 V, I_{OL} = 2.1 mA$	— — 0.4 V			
Input High Voltage ⁴	V _{IH}		V _{CC} x 0.7 V _{CC} + 0.5 V			
Input Low Voltage ⁴	V _{IL}		-1.0 — V _{CC} x 0.3 V			
Input Leakage Current	ILI	V _{IN} = V _{CC} max.	20 μΑ			
Output Leakage Current	I _{LO}		— — 20 μA			

1. Stresses violating the conditions listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only. Functional operation of the device outside these conditions or those indicated in the operational sections of this specification is not implied. Exposure to these conditions for extended periods may affect reliability.

2. Tested initially and after any design or process changes that may affect these parameters.

3. Test conditions: $T_A = 25^{\circ}C$, f = 1 MHz, Vcc = 5.0V.

4. V_{IL} min and V_{IH} max are reference only and are not tested.



FT24C256 256K-bit 2-Wire Serial

CMOS EEPROM

Power Supply Characteristics $(T_A = -55^{\circ}C \text{ to } +175^{\circ}C)$							
Parameter	Symbol	Conditions	ſ	∕lin	Тур	Max	Units
VCC Operating Current	I _{cc1}	Read at 400 KHz (V _{CC} = 5V)		-/	-	2.5	μA
VCC Operating Current	I _{CC2}	Write at 400 KHz (V _{CC} = 5V)		-	-	3.5	μΑ
Standby Current	I _{SB} 2	V _{CC} = 2.5V		_	(F)	4	μΑ
Standby Current	I _{SB} 3	V _{CC} = 5.0V	/	-	-	12	μA
			/ /				

AC Electrical Characteristics $(T_A = -55^{\circ}C \text{ to } +175^{\circ}C)$						
Parameter	Symbol	2.5V Min	7 -5.5V Max	4.5V - Min	5.5V¹ Max	Units
SCL Clock Frequency	f _{SCL}	0	400	0	1000	KHz
Noise Suppression Time ¹	Т		50		50	ns
Clock Low Period	t _{LOW}	1.2	_	0.6	_	s
Clock High Period	t _{HIGH}	0.6	<	0.4	_	s
Bus Free Time Before New Transmission	t _{BUF}	1.2	_	0.5	_	s
Start Condition Setup Time	t _{SU:STA}	0.6	_	0.25	_	s
Stop Condition Setup Time	t _{SU:STO}	0.6	_	0.25	_	s
Start Condition Hold Time	t _{HD:STA}	0.6	_	0.25	_	s
Stop Condition Hold Time	t _{HD:STO}	0.6	_	0.25	_	S
Data In Setup Time	t _{SU:DAT}	100	_	100	_	ns
Data In Hold Time	t _{HD:DAT}	0		0	_	ns
WP pin Setup Time	t _{SU:WP}	0.6	_	0.6	_	s
WP pin Hold Time	t _{HD:WP}	1.2	_	1.2	_	s
Data Out Hold Time (SLC Low to SDA Data Out Cha	t _{DH} nge)	50	—	50	—	ns
Clock to Output (SCL Low to SDA Data Out Valio	t _{AA}	50	900	50	550	ns
SCL and SDA Rise Time ¹	t _R	_	300	_	300	ns
SCL and SDA Fall Time ¹	t _F	_	300	_	100	ns
Write Cycle Time	t _{WR}	_	10	_	5	ms

1. This parameter is characterised but not 100% tested.



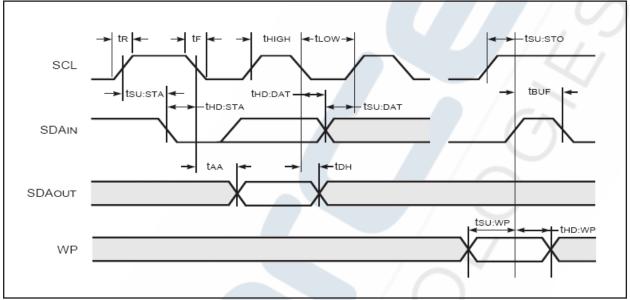
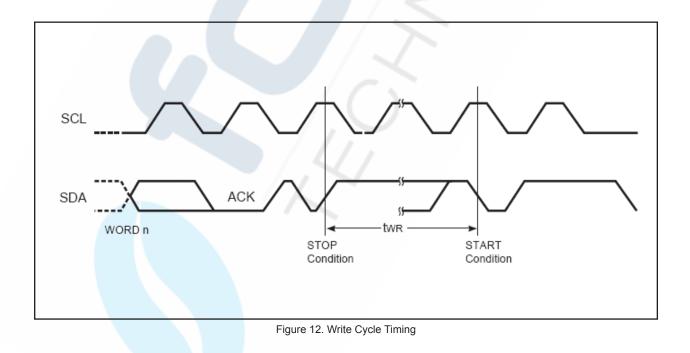


Figure 11. Bus Timing





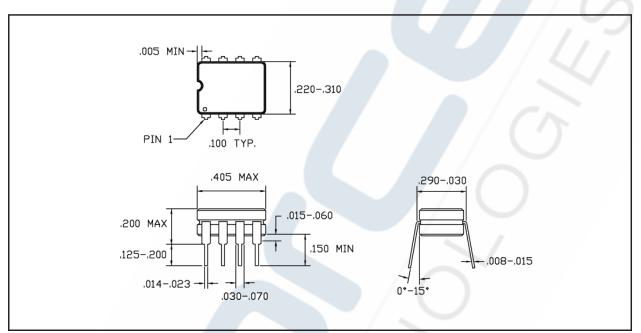


Figure 13. 8-pin PDIP and CDIP package outline

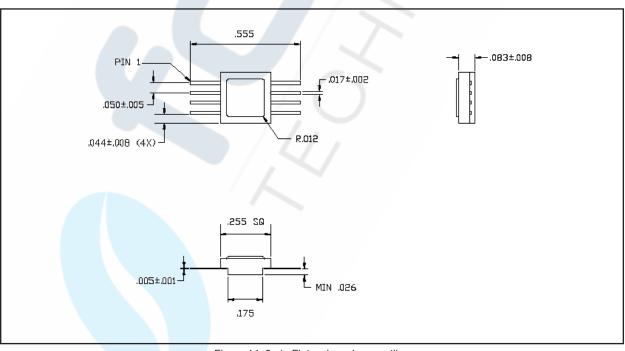


Figure 14. 8-pin Flatpack package outline



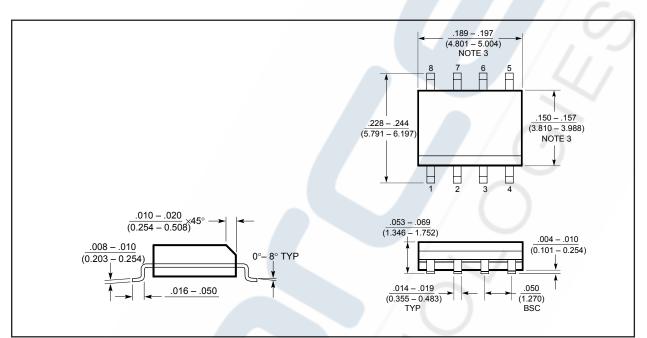


Figure 15. 8-pin SOIC package outline

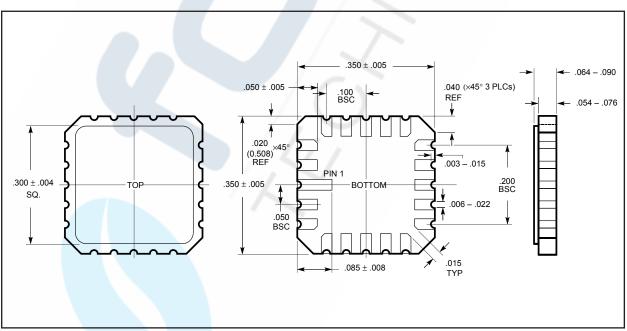


Figure 16. 20-pin LCC package outline



256K-bit 2-Wire Serial CMOS EEPROM

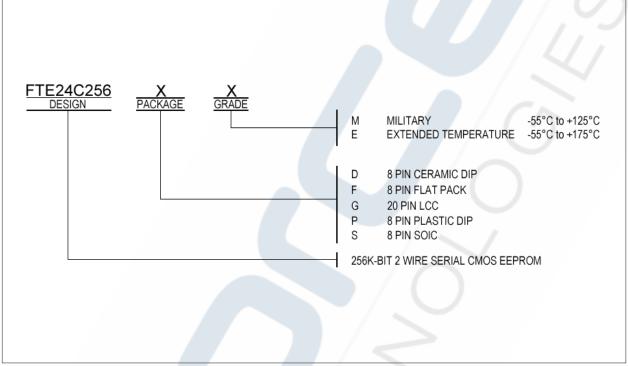


Figure 17. Order Information



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